

Optimal Source Characteristics for Micro-Beams for Macromolecular Crystallography

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Upgrade of the Technical Facilities of the SBC

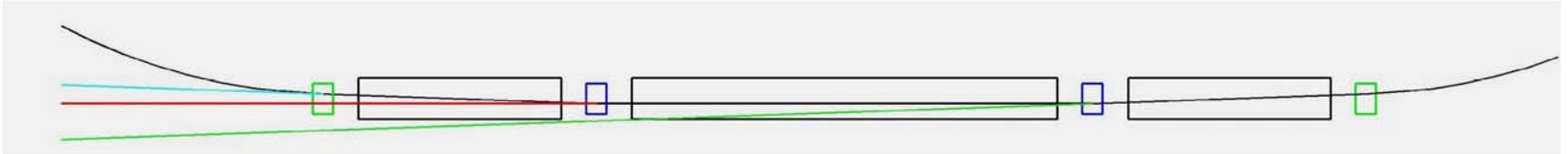
Aims:

- More than Doubling Capacity of SBC Sector
- Adding Microbeam Capability
(no PX beamline with microfocus at the APS at present)
- Upgrading Existing Beamlines to 3rd Generation Technology
- Improving Stability and Reliability of Beam on Sample (R&D)
- Preparing X-ray Optics for 200 mA Beam Current (R&D)
- Fully Integrated Auto-Mounting and Auto-Centering of Samples (R&D)

Doubling Capacity of SBC Sector

- Adding two undulator beamlines
- Three independent undulators in the straight section
- Undulator sequence: short - long - short
- X-ray beam directions:
0.5 mrad outboard; center line; 0.5 mrad inboard
- Short undulators (new design): 1.0 m long, 3.1 cm period
- Long undulator (new magnetic structure) : 2.1 m long, 3.1 cm period
- All three beamlines can be operated independently of each other:
independent wavelength change, independent access to endstation
- Flux into central cone $\sim L^{1.05\dots 1.2}$ (L = length of undulator)

Three Undulators in Straight Section



- One beam pipe for all three undulators, 4.8 m long, new design (with integral particle BPMs before, between, and after undulators)
- Between undulators:
Deflector magnets (+ corrector magnet?): each set about 0.35 m long
- Length budget: $1.0 \text{ m} + 0.35 \text{ m} + 2.1 \text{ m} + 0.35 \text{ m} + 1.0 \text{ m} = 4.8 \text{ m}$
- Need new front end with triple beam mask (design, manufacture by APS)
- Need to adapt new hard X-ray BPMs for triple beam (R&D by GR & APS)

Source Sizes, X-ray Beam Divergences and Flux into Central Cone vs. Undulators Length

APS in lower emittance mode (<http://www.aps.anl.gov/asd/oag/beamParameters.html>):

natural emittance 2.5 nm-rad, coupling 0.01, $\beta_x = 19.5$ m, $\beta_y = 2.87$ m, $\alpha_x = 0$, $\alpha_y = 0$,

$\eta_x = 0.172$ m, $\eta_y = 0$, $\eta_{x'} = 0$, $\eta_{y'} = 0$, $\delta E/E = 0.000965$

→

$\sigma_x = 275.3$ μm , $\sigma_y = 8.5$ μm , $\sigma_{x'} = 11.3$ μrad , $\sigma_{y'} = 3.0$ μrad

Diffraction limited radiation source size and angle for undulators of length L:

at $E_{\text{phot}} =$	6 keV	12 keV	18 keV	6 keV	12 keV	18 keV
L		σ_r			$\sigma_{r'}$	
(m)		(μm)			(μrad)	
2.4	2.5	1.7	1.4	6.7	4.7	3.9
2.1	2.3	1.6	1.3	7.1	5.0	4.1
1.0	1.6	1.1	0.9	10.5	7.5	6.1

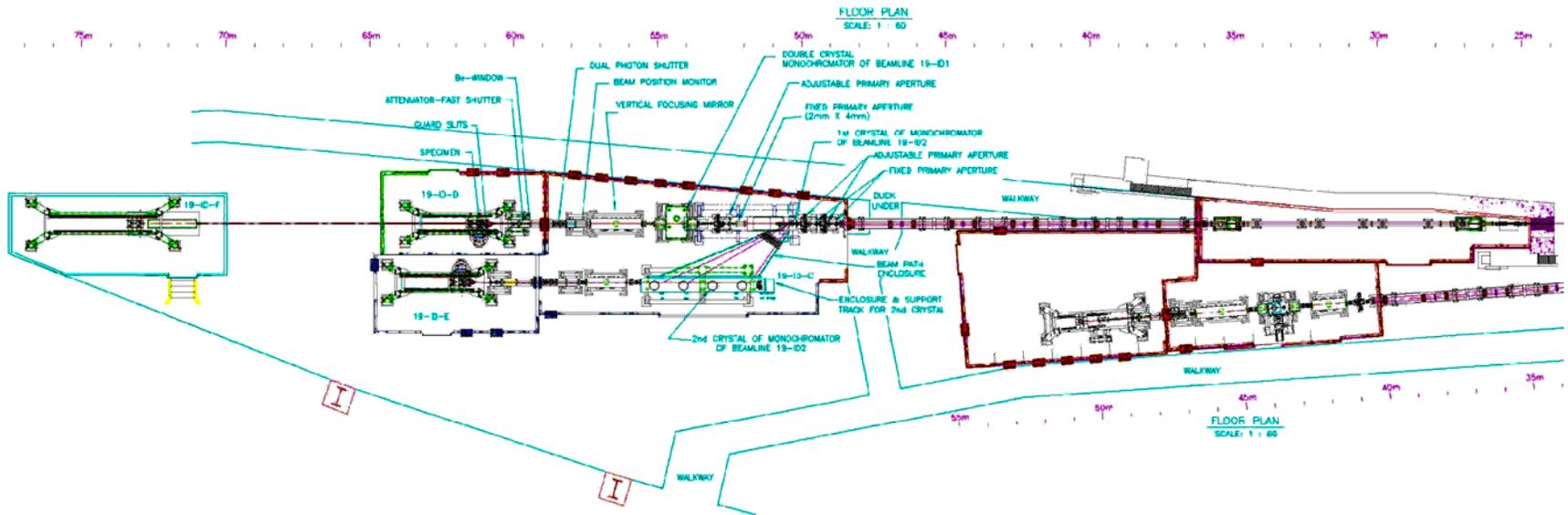
Radiation source size and angles and flux into central cone at 12 keV for undulator of length L and magnetic period P:

L	P	Σx	Σy	$\Sigma x'$	$\Sigma y'$	Flux 1 st	Flux 3 rd
(m)	(cm)	(μm)	(μm)	(μrad)	(μrad)	(10^{14} ph/s/0.1%BW)	
2.4	3.3	275.3	8.7	12.2	5.6	2.30	3.67
2.1	3.1	275.3	8.6	12.4	5.8	2.88	3.56
1.0	3.1	275.3	8.6	13.6	8.1	1.17	1.44

Three Undulator Beamlines Upgrade

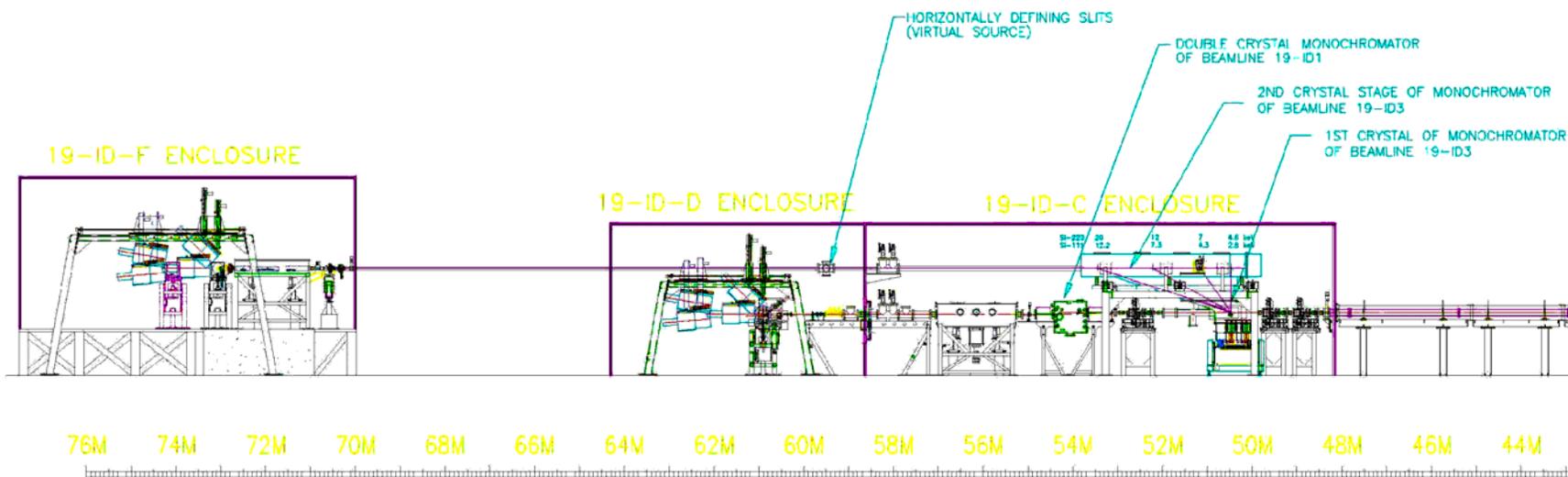
Overview

Plan View



Three Undulator Beamlines Upgrade

Overview Elevation



Vertically Offset Beamline

(Outboard Beam)

- Vertically deflecting monochromator
- Dual cut 1st crystal: Si-111 and 220
- Monochromatic beam 1 m vertically offset
- 2nd crystal stage on long track with crystal changer (111 and 220)
- Photon energy range: 3 - 20 keV (0.62 - 4 Å)
(Bragg-angles 9.2°-45°, Si-111: 2.8 -12.2 keV, Si-220: 4.6 -20 keV)
- Minimum focal size: 1 μm x 3 μm FWHM (hor x ver)
- Beam transport through center beam line endstation above detector positioner
- New endstation enclosure and beam transport

Need for Microbeam

- Very small crystals: reduce scatter from non-crystalline material
- Selective exposure of small crystal volumes:
 - very asymmetric shape of crystal (e.g. needle): reduce scatter from non-crystalline material
 - very small, well ordered domains
- Reducing radiation damage in exposed volume:
 - photo-electrons travel several μm ($\sim 6\mu\text{m}$ for 18 keV initial energy)
 - large fraction of damaging energy is not deposited in the illuminated volume for micrometer size beams
 - energy deposit per distance traveled is not uniform, very high at end of travel
- Photo-electrons ejected predominantly in direction of electric field vector

From: Colin Nave & Mark A. Hill, JSR (2005), 12, 299-303

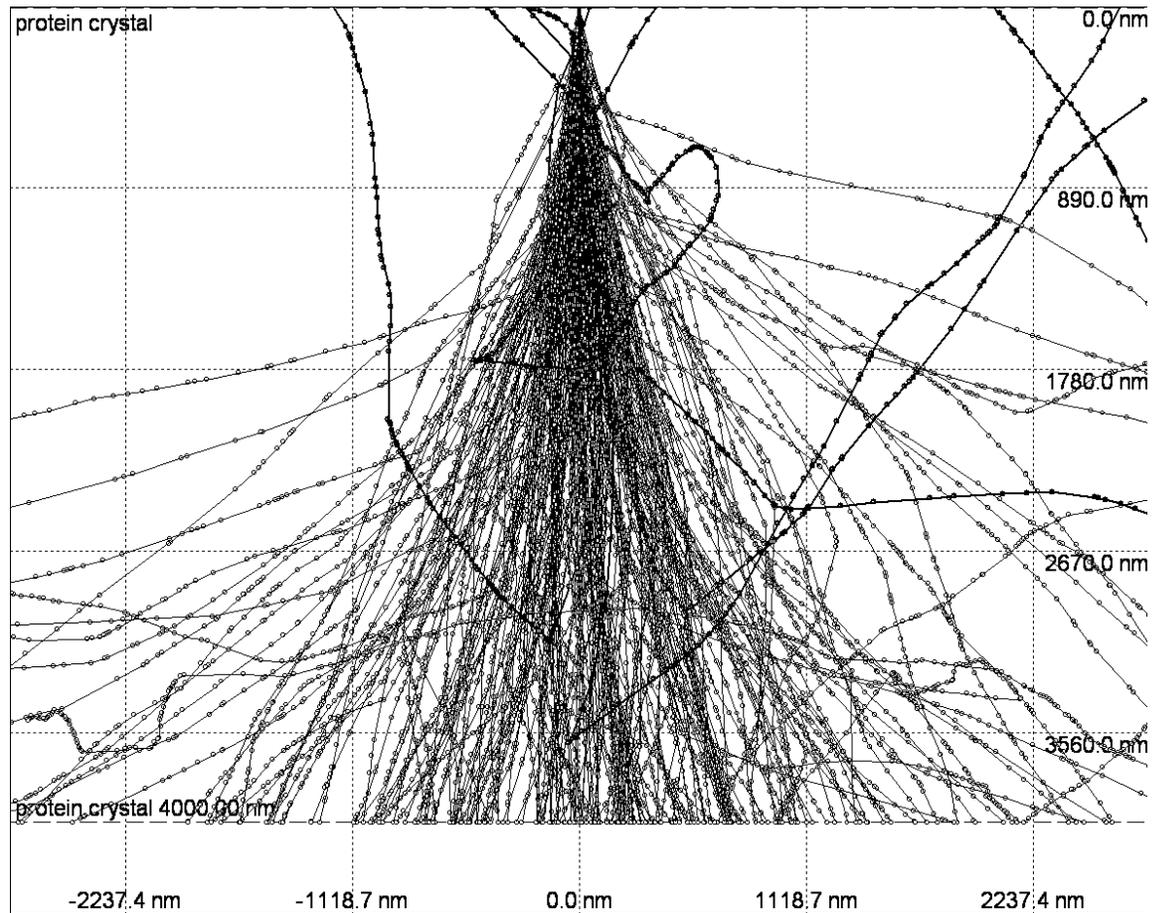


Figure 3. A simulation of tracks, created by electrons of 30 keV energy inside a protein crystal, calculated using the Monte-Carlo program Casino.

From: Colin Nave & Mark A. Hill, JSR (2005), 12, 299-303

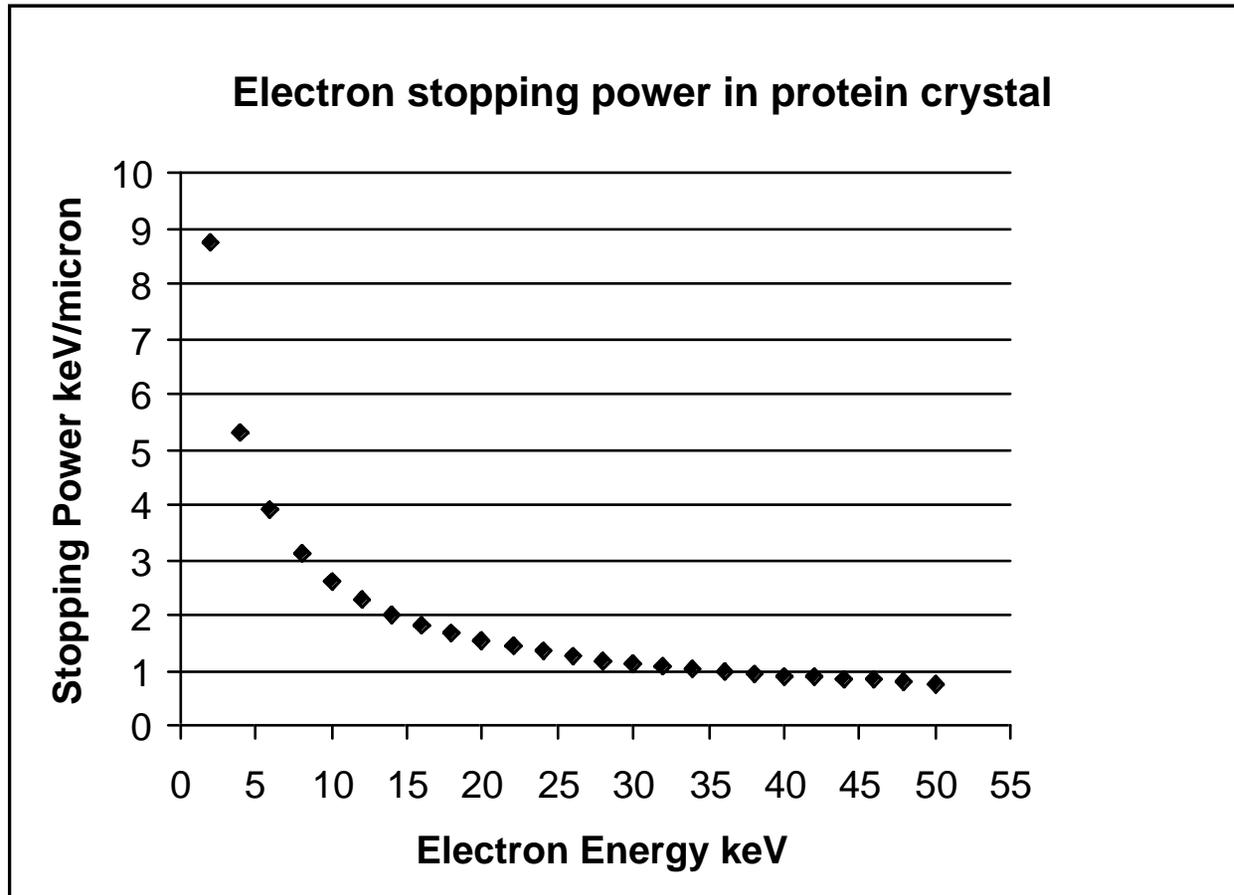
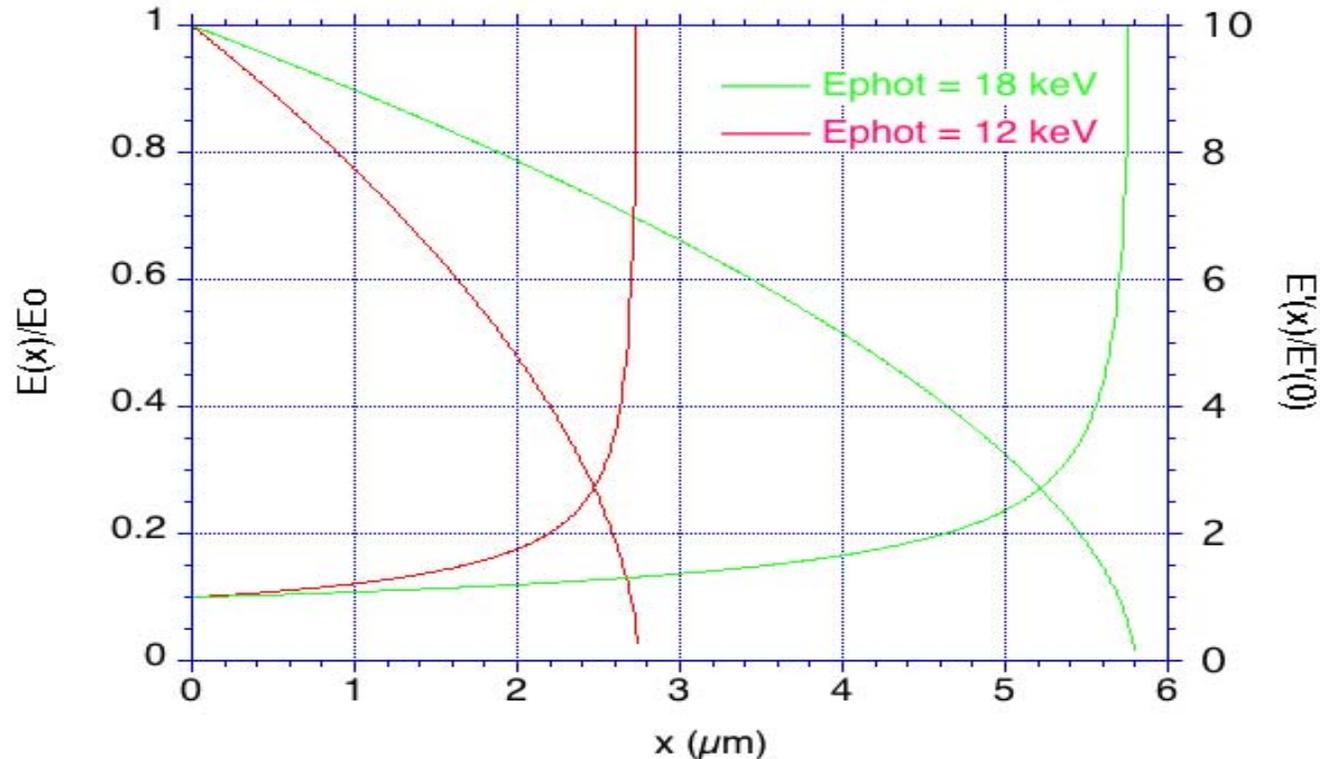


Figure 1. The electron stopping power as a function of electron energy inside a protein crystal of density 1.17g/cm³.

Energy Loss of Photo-Electrons and Deposited Dose vs. Distance Traveled

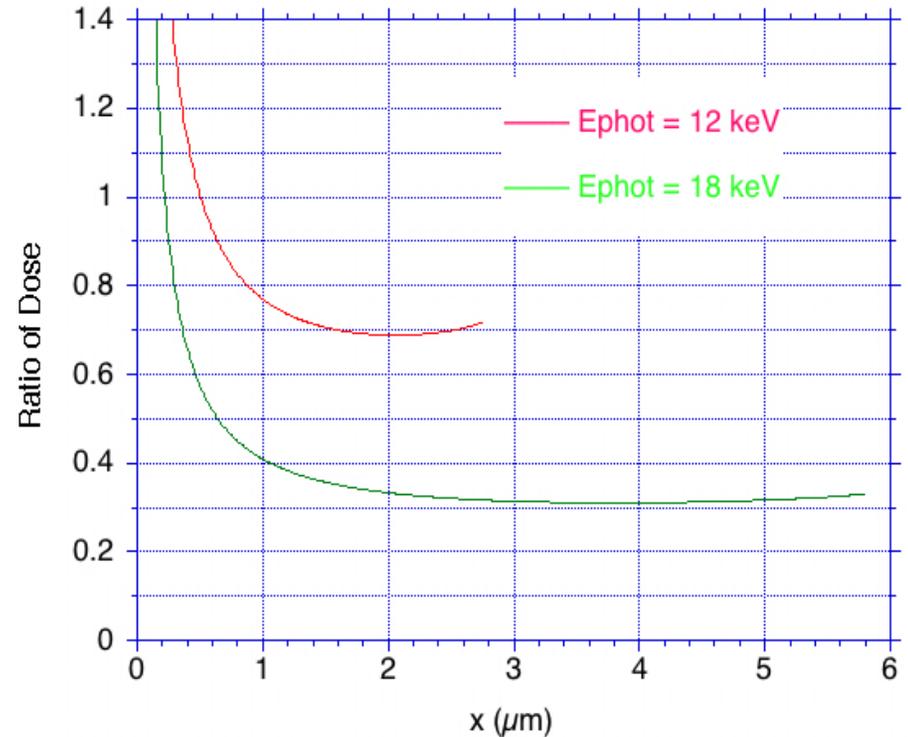
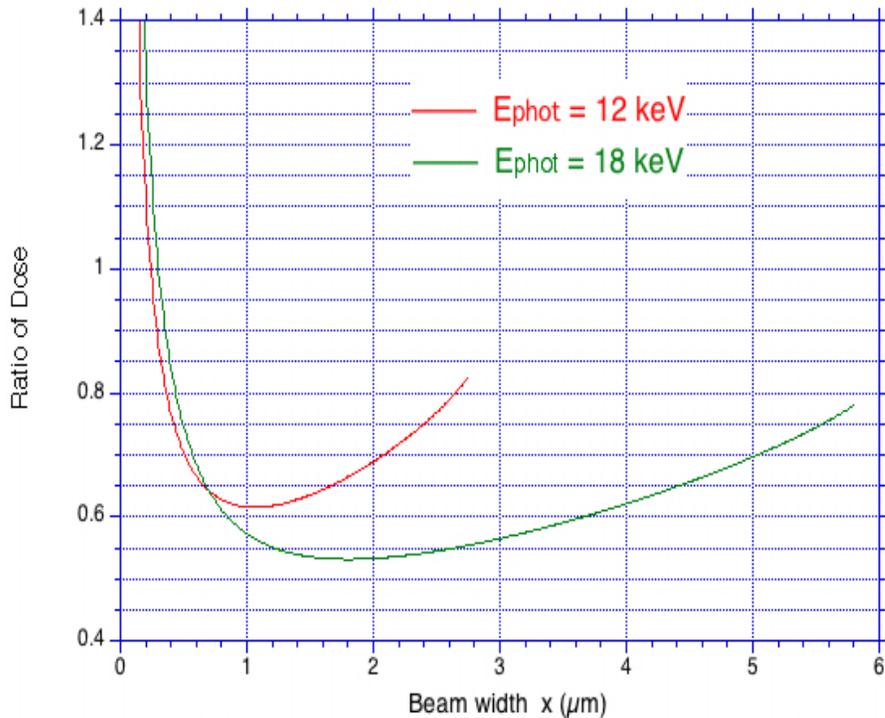


Ratio of energy $E(x)$ of photo-electron at distance x from starting point to initial energy E_0 (left scale).

Ratio of energy loss dE/dx of photo-electron at distance x from starting point to energy loss at $x = 0$ (right scale)

Average binding energy = 600 eV

Reduction of Dose to Exposed Crystal Volume vs. Beam Width



Ratio of Dose to Exposed Crystal Volume with Beam of Width x vs. Uniform Illumination

Left panel: Exposure of width x and no exposure of damaged volumes either side vs. uniform illumination
Exposure adjusted for equal integrated intensities. Average binding energy = 600 eV

Right panel: Exposure of width x vs. uniform illumination of microcrystal of $5 \mu\text{m}$ size.
Exposure adjusted for equal integrated intensities. Average binding energy = 600 eV

Need for Microbeam

- Need beam of 1 - 2 μm horizontal width at 18 keV photon energy
- Vertical beam size can be larger:
 - is not the predominant direction of photo-electrons
 - due to rotation around horizontal axis, exposed volume is larger than beam size
- Source size is large (650 μm FWHM) in direction of polarization (horizontal, only 20 μm FWHM in vertical direction)
- Large horizontal demagnification required:
 - two step demagnification:
 - (1) normal demagnifying beamline optics
 - (2) focusing on horizontal defining slits = virtual source
 - (3) re-imaging virtual source on sample

Vertically Offset Beamline

(Outboard Beam)

- Optical design:

Horizontally (vertically after 45° mirror): two stage demagnification

- imaging source on slits with focusing 2nd crystal, 8.35:1 demag
- reducing effective horizontal source size with slits, $\sim 4x$
- re-imaging virtual source with horizontally focusing mirror, 8.25:1 demag, 500 mm long bimorph, 1.46 m from sample

Flat mirror at 45° with horizontal plane flips horizontal and vertical virtual source, 500 mm long, 0.93 m from sample

Vertically (horizontally after 45° mirror): one stage demagnification

- horizontally focusing mirror, 300 mm long bimorph, ~ 500 mm from sample

- Endstation instrumentation:

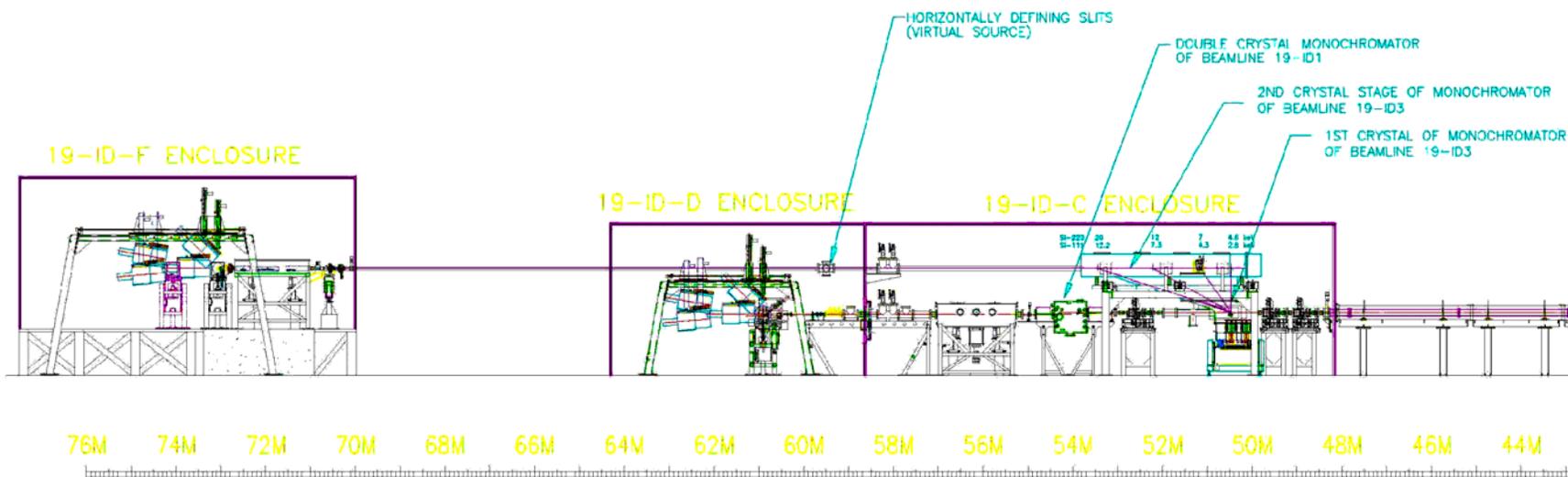
Single axis goniostat, sub-micrometer runout

On-axis, high magnification sample alignment microscope

Standard detector positioner

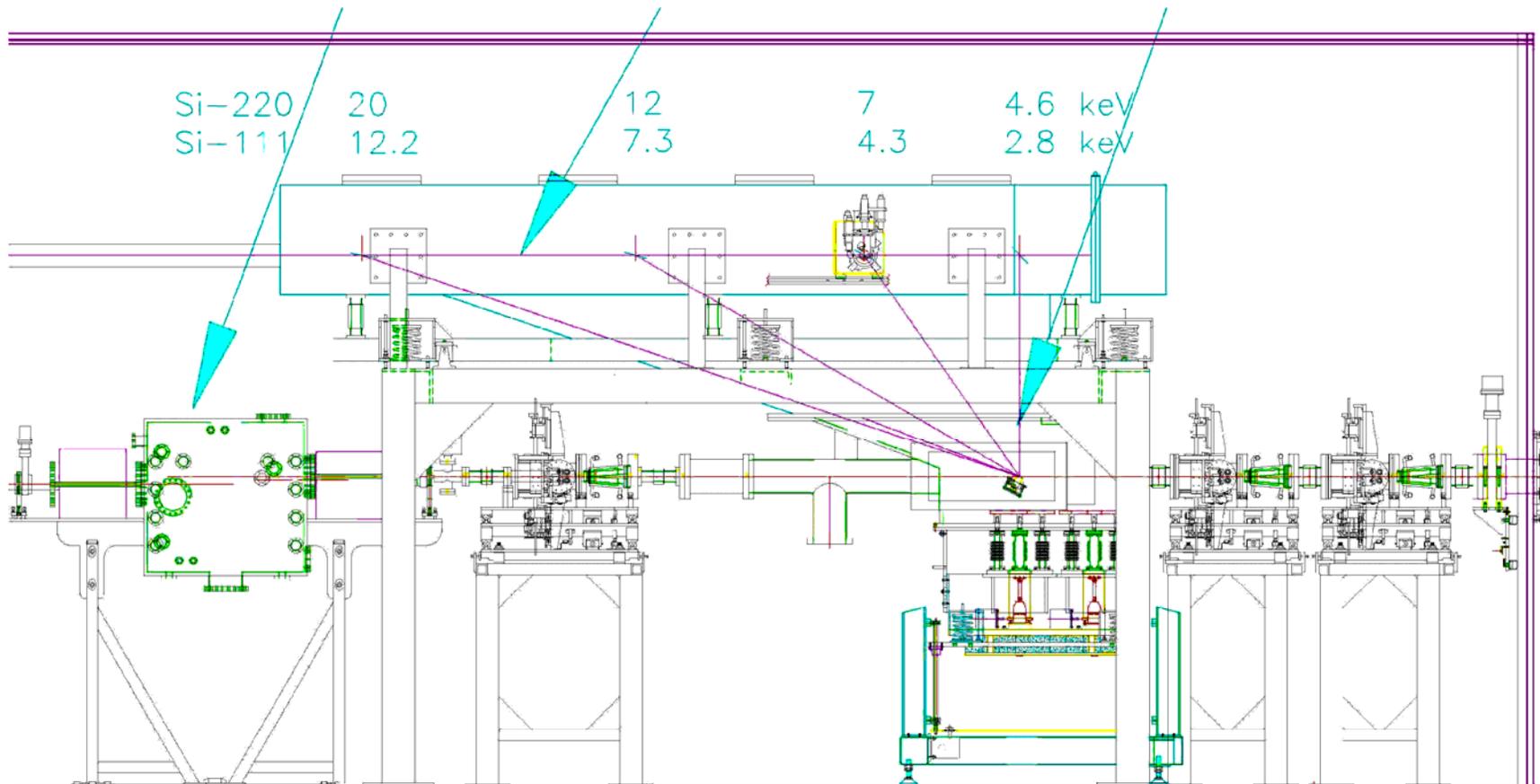
Three Undulator Beamlines Upgrade

Overview Elevation



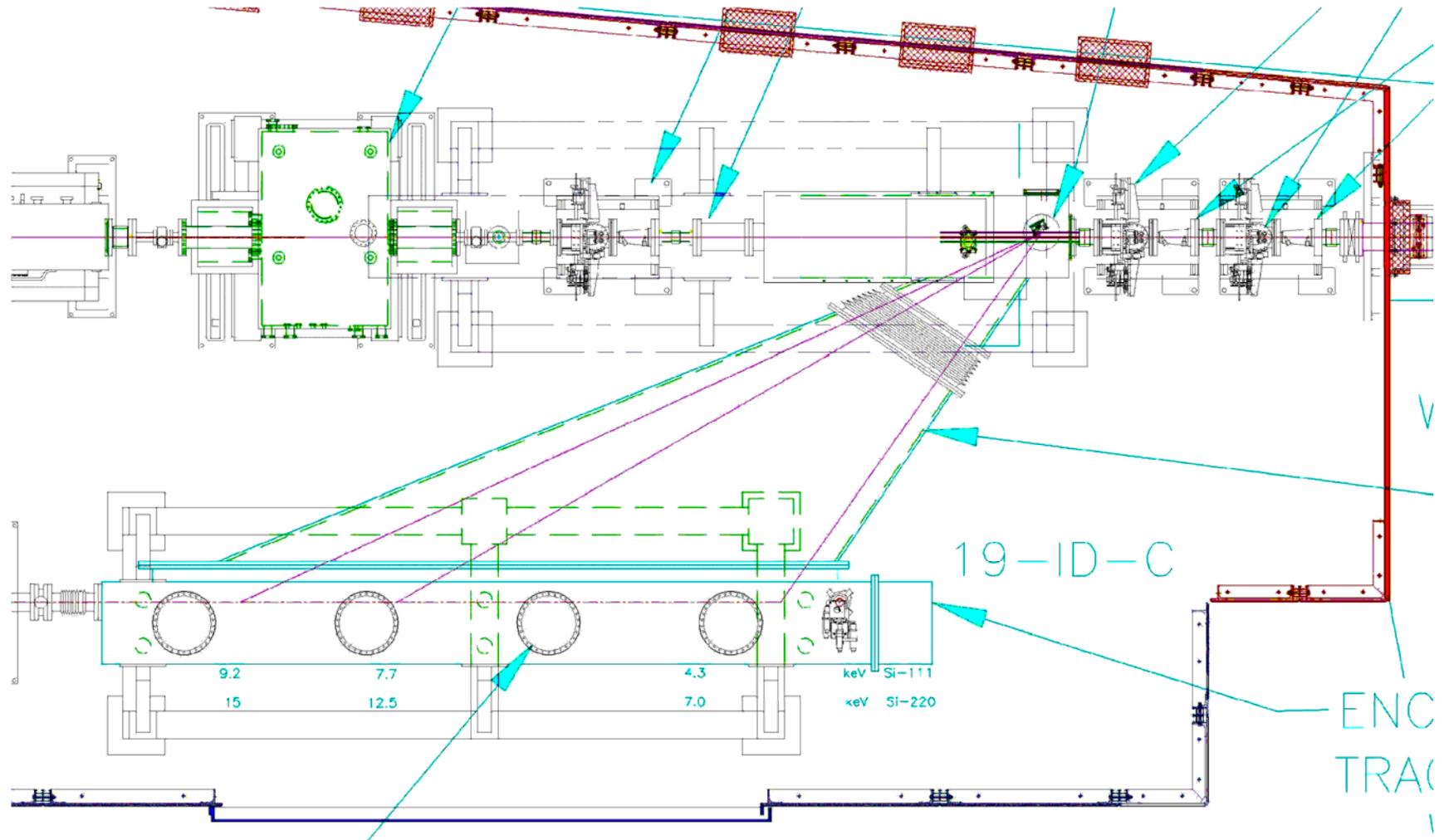
Three Undulator Beamlines Upgrade

Vertically Deflecting Monochromator



Three Undulator Beamlines Upgrade

Horizontally Deflecting Monochromator

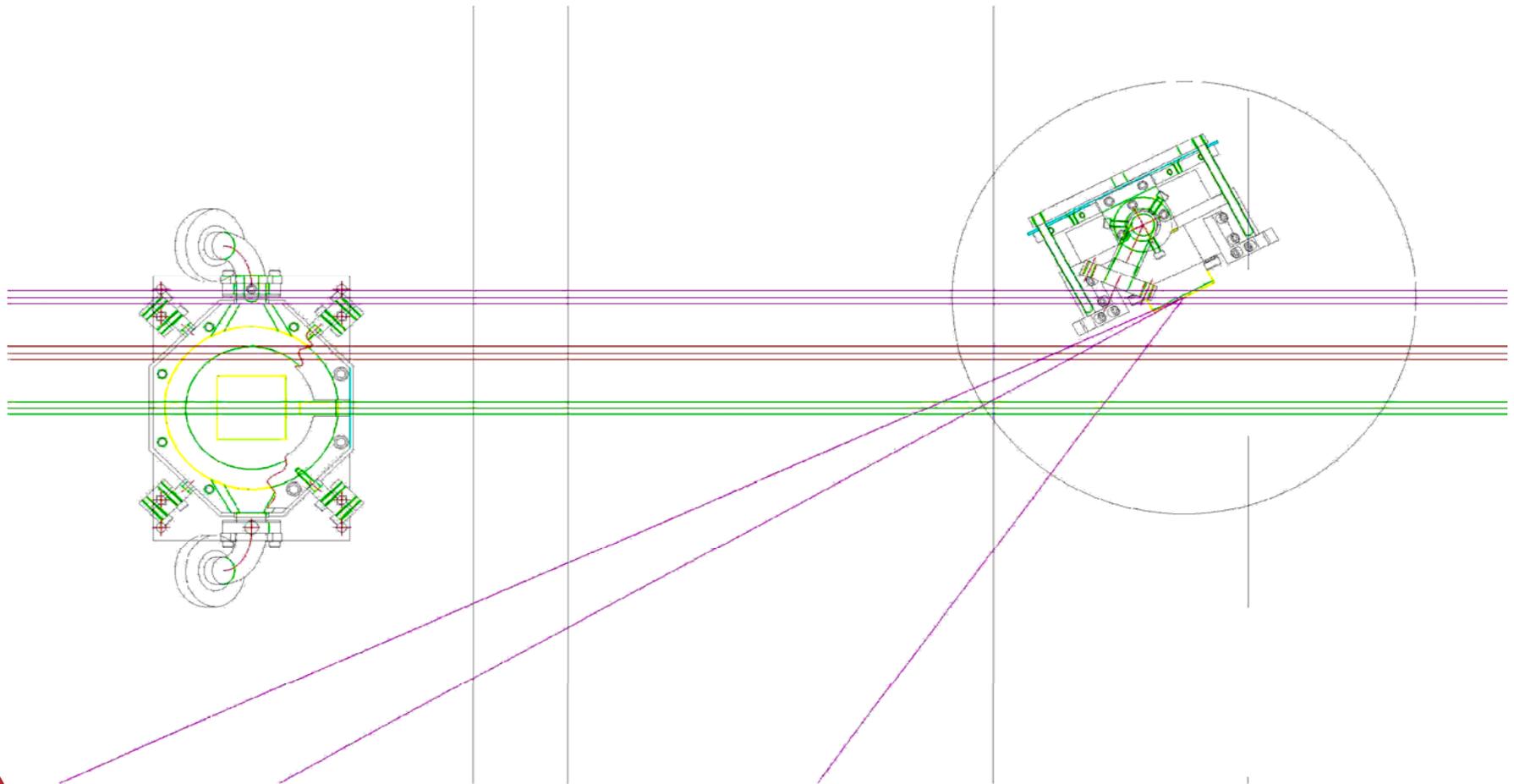


Three Undulator Beamlines Upgrade

Three Undulator Beams and First Monochromator Crystals

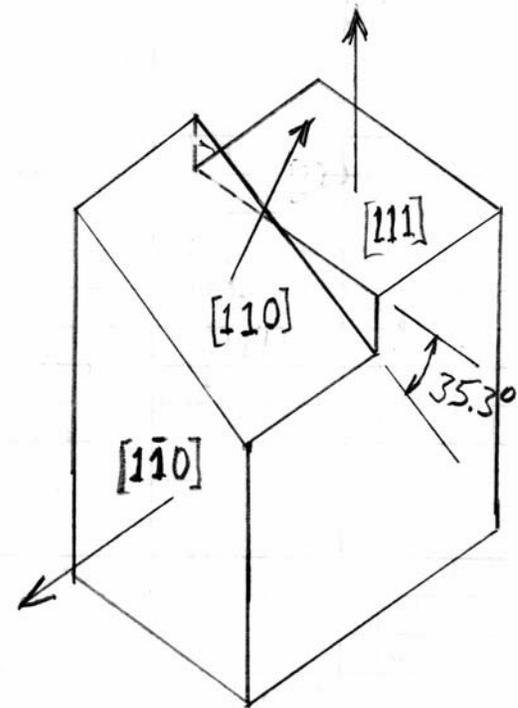
Vertically Deflecting

Horizontally Deflecting

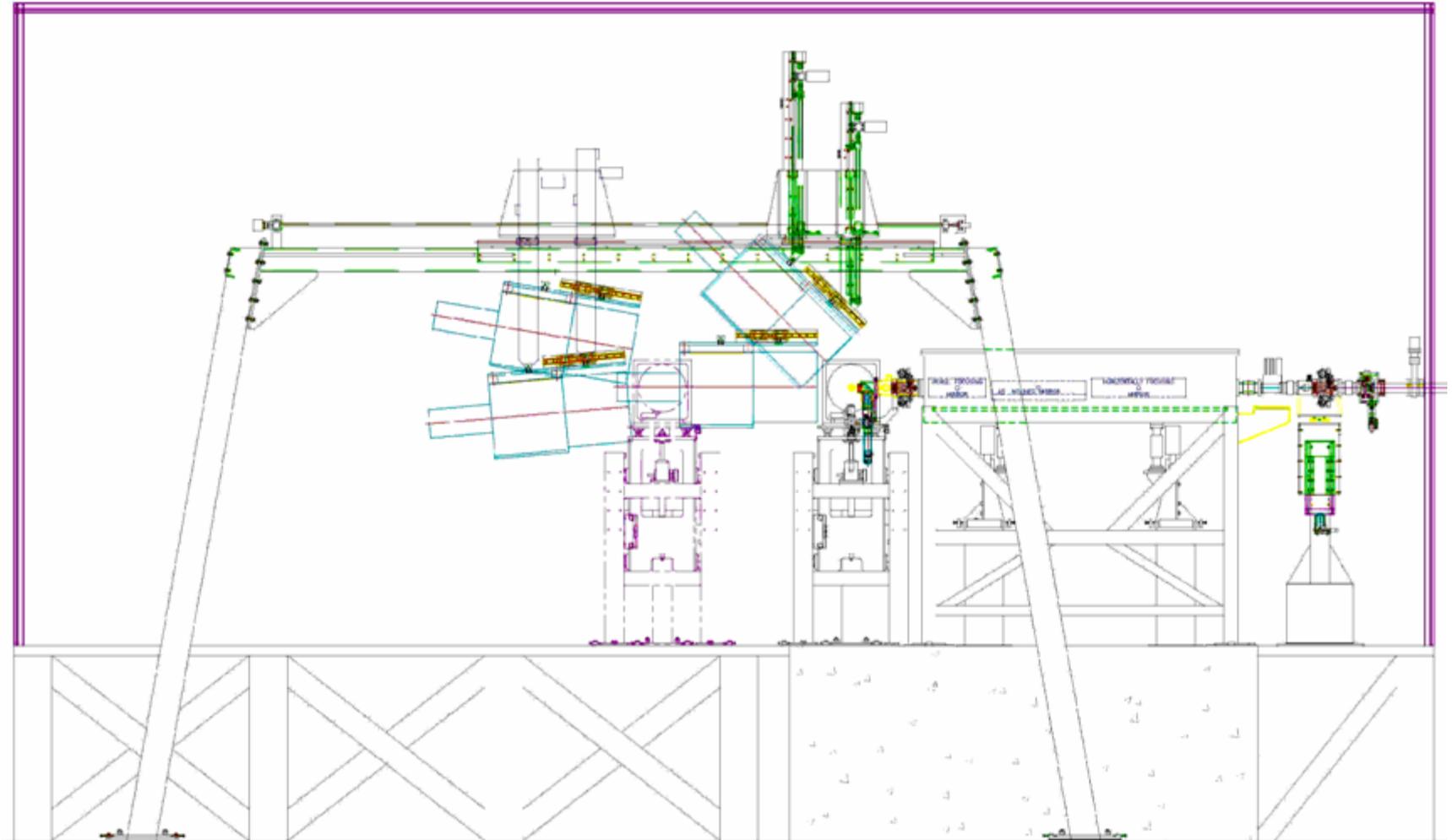


Dual Cut First Monochromator Crystal (Liquid Nitrogen Cooled for ID)

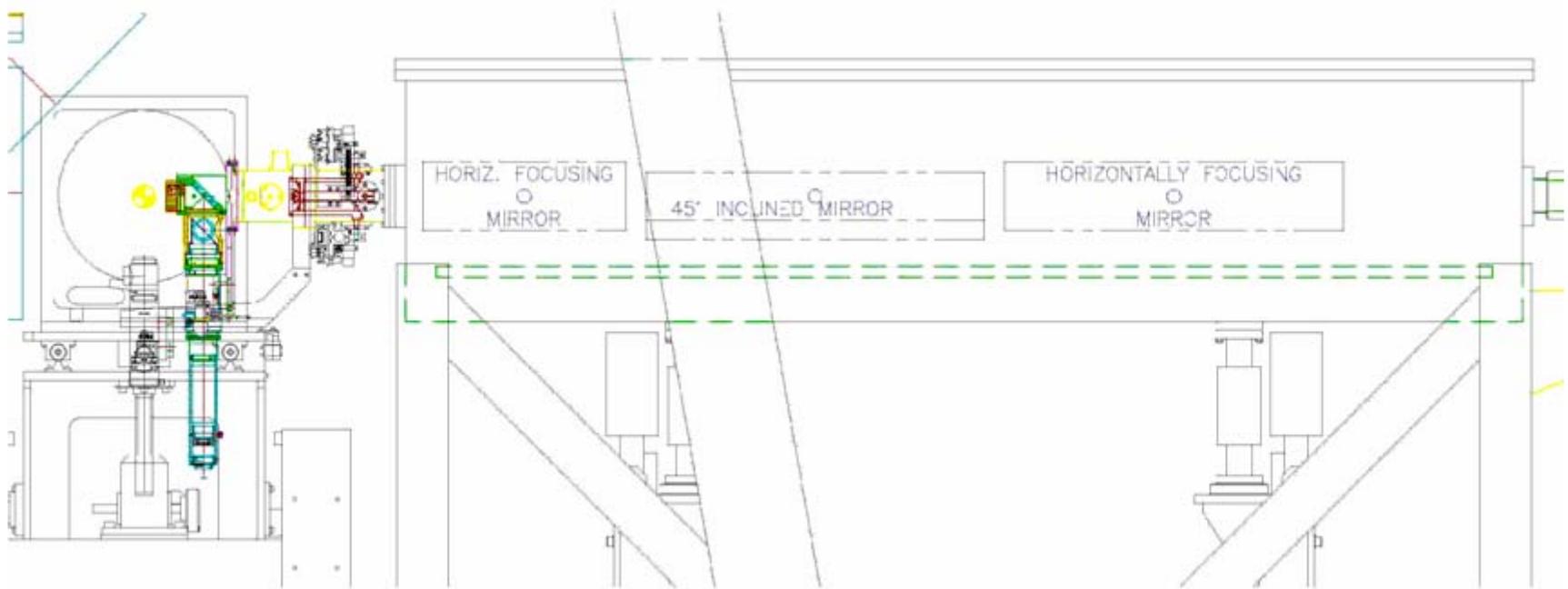
- Change of energy range by lateral translation of crystal
- No warm-up of cryo-cooled crystal and change of LN2 connections
- Extends energy coverage for limited range of Bragg-angles
- Requires robotic changer of focusing second crystal



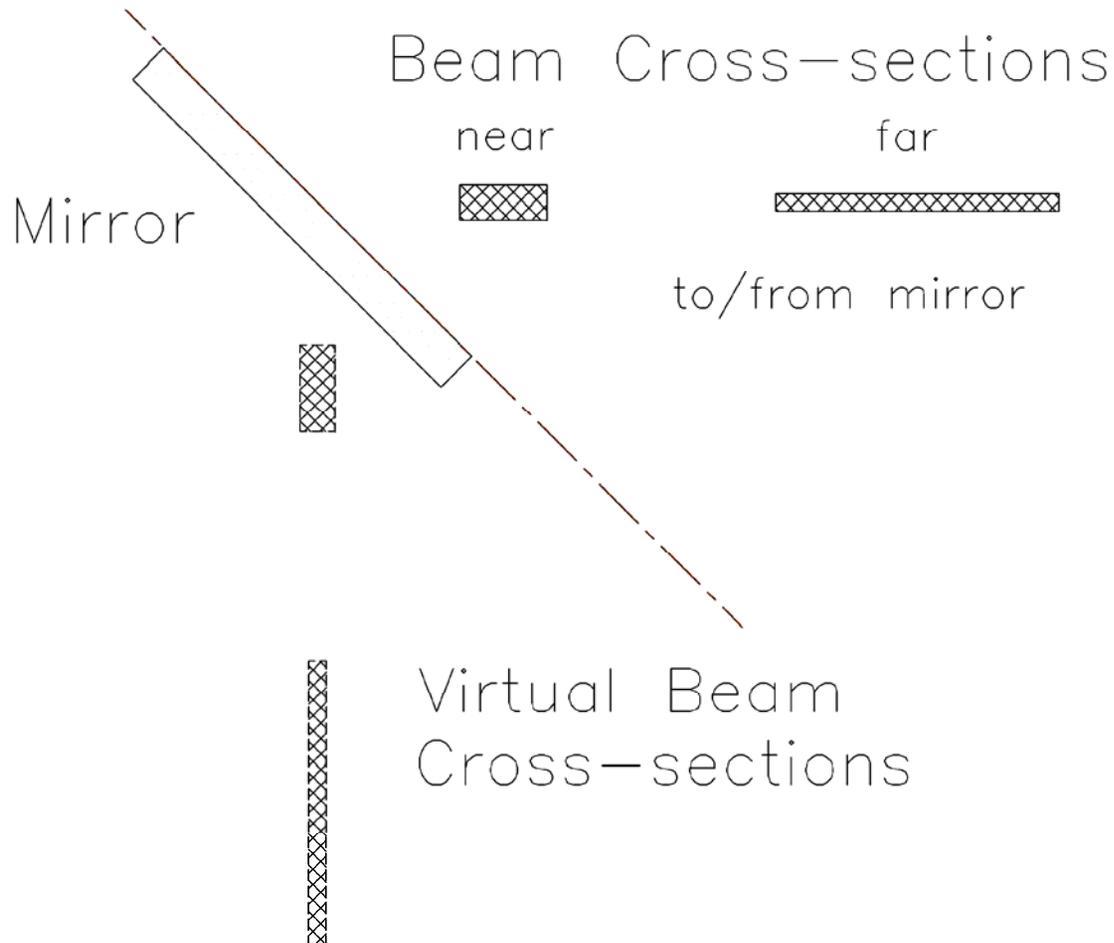
Vertically Offset Beamline Endstation



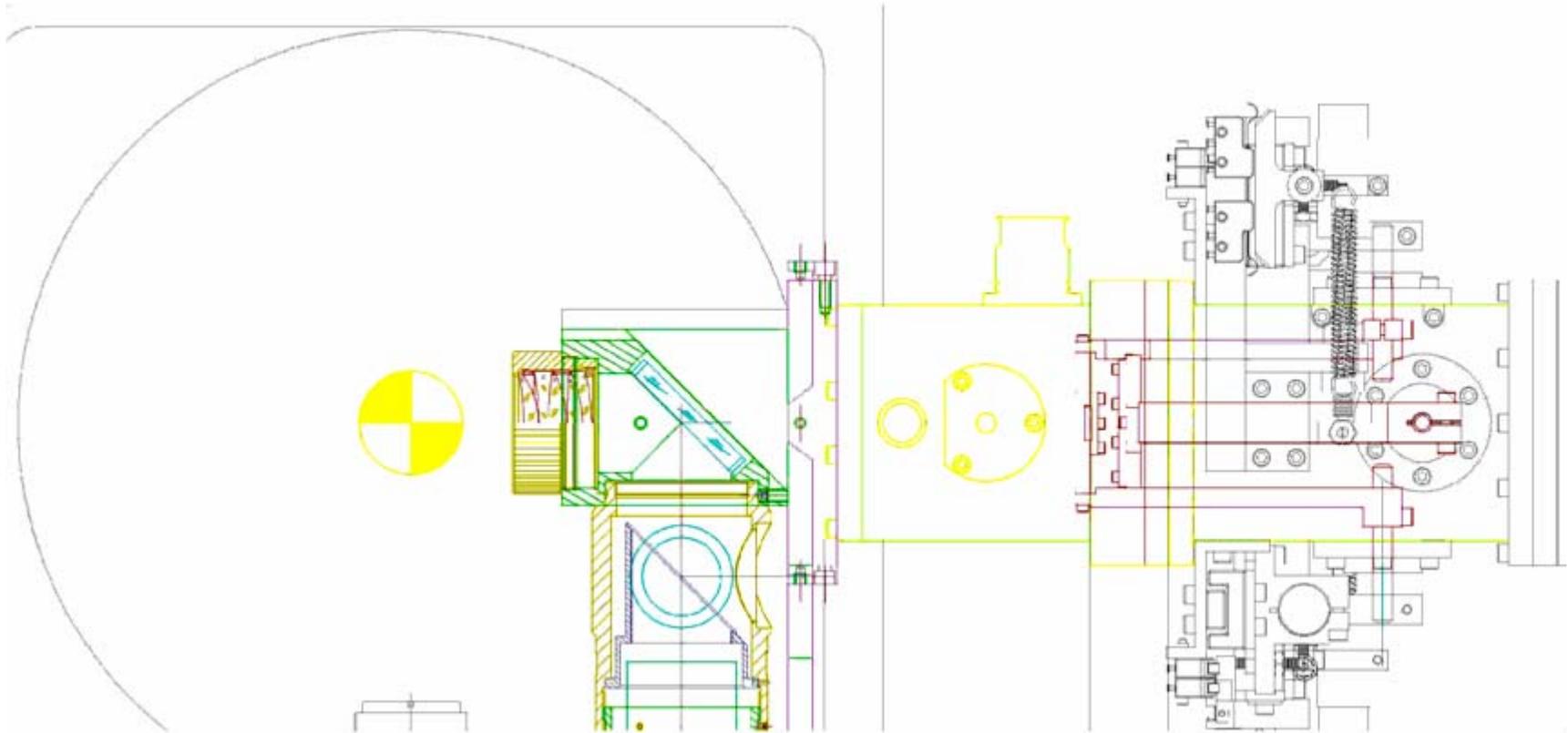
Vertically Offset Beamline Focusing Mirrors and Sample Stage



Rotation of Beam Cross-Section by 45° Mirror



Vertically Offset Beamline Sample Area



Size and Flux Estimates of Microbeam

- Imaging horizontal source on slits
 - source to 2nd crystal at 18 keV (Si-220) 53.30 m
 - 2nd crystal to slits 6.38 m
 - demagnification 8.35:1
 - width of horizontal focus 78 μm FWHM
- Imaging virtual source (slits) on sample
 - slits to focusing mirror 12.04 m
 - focusing mirror to sample 1.46 m
 - demagnification 8.25:1
- Size of image of slits at sample
 - aberration free image of 20 μm wide slits 2.4 μm
 - bimorph allows to shape mirror to required elliptical figure
 - aberrations determined by residual surface figure error
 - Gaussian figure error of 0.3 μrad rms creates beam size of 2.1 μm FWHM
 - convoluted size of image of 20 μm slits 3.2 μm FWHM
 - of 10 μm slits 2.4 μm FWHM

Size and Flux Estimates of Microbeam

- Imaging vertical source on sample
 - source to focusing mirror 72.68 m
 - focusing mirror to sample 0.50 m
 - demagnification 145:1
- Size of image of vertical source at sample
 - aberration free image 0.14 μm FWHM
 - bimorph allows to shape mirror to required elliptical figure
 - aberrations determined by residual surface figure error
 - Gaussian figure error of 0.3 μrad rms creates beam size of 0.7 μm FWHM
 - convoluted size of image 0.7 μm FWHM

Size and Flux Estimates of Microbeam

Flux at sample

- Loss at slits
 - fraction of 78 μm wide beam passing 20 μm slits 0.238
 - 10 μm slits 0.121
- Angular acceptance of mirror imaging slits
 - mirror length 500 mm, effective 400 mm
 - grazing angle 4 mrad
 - distance to slits 12.04 m
 - angular acceptance from slits 133 μrad
 - angular acceptance from source at 8.35:1 demagnification 15.9 μrad
- Angular acceptance of 2nd focusing mirror
 - mirror length 300 mm, effective 200 mm
 - grazing angle 4 mrad
 - distance to source 72.68 m
 - angular acceptance from source 11.0 μrad

Size and Flux Estimates of Microbeam

- Flux from undulator 2.37*10¹³ ph/s/0.1%BW
 - 1m long (eff. 0.93 m), 3.1 cm magnetic period
 - at $E_{\text{phot}} = 18$ keV
 - into 15.9 μrad horizontal and 11.0 μrad vertical angle
- Passing through 20 μm slits 0.238
- Si-220 double crystal bandwidth $\sim 4.6 \cdot 10^{-5}$
- Losses in windows, other 0.8
- Estimate of flux on sample 2.1*10¹¹ ph/s
- Estimate of flux density at sample 9*10¹⁶ ph/s/mm²
- Convergence angles of flux on sample
 - horizontal 1.1 mrad
 - vertical 1.6 mrad
- Exposure time to reach dose limit $D_{1/2} = 4.3 \cdot 10^7$ Gy 2 seconds

Microfocus Beamline After APS Upgrade

- Optical design:
 - basically the same
 - need maximum beamline length for high demagnification
 - but can be simplified:

Horizontally: one stage demagnification

horizontally focusing mirror, 300 mm long bimorph, ~ 500 mm from sample

Vertically: one stage demagnification

vertically focusing mirror, 400 mm long bimorph, ~ 900 mm from sample

- Endstation instrumentation: same

Size and Flux Estimates of Microbeam After APS Upgrade

- APS Upgrade parameters (Case: small size):
 $\sigma_x = 35 \mu\text{m}$, $\sigma_x' = 22 \mu\text{rad}$, $\sigma_y = 7.3 \mu\text{m}$, $\sigma_y' = 1.1 \mu\text{rad}$
2.1 m long undulator, $E_{\text{phot}} = 18 \text{ keV}$: $\sigma_r = 1.3 \mu\text{m}$, $\sigma_r' = 4.1 \mu\text{rad}$
 $\Sigma_x = 35 \mu\text{m}$, $\Sigma_x' = 22.4 \mu\text{rad}$, $\Sigma_y = 7.4 \mu\text{m}$, $\Sigma_y' = 4.2 \mu\text{rad}$
- Imaging horizontal source on sample
 - source to focusing mirror 72.68 m
 - focusing mirror to sample 0.50 m
 - demagnification 145:1
- Size of image of horizontal source at sample
 - aberration free image 0.57 μm FWHM
 - bimorph allows to shape mirror to required elliptical figure
 - aberrations determined by residual surface figure error
 - Gaussian figure error of 0.3 μrad rms creates beam size of 0.7 μm FWHM
 - convoluted size of image 0.9 μm FWHM

Size and Flux Estimates of Microbeam After APS Upgrade

- APS Upgrade parameters (Case: small size):
 $\sigma_x = 35 \mu\text{m}$, $\sigma_{x'} = 22 \mu\text{rad}$, $\sigma_y = 7.3 \mu\text{m}$, $\sigma_{y'} = 1.1 \mu\text{rad}$
2.1 m long undulator, $E_{\text{phot}} = 18 \text{ keV}$: $\sigma_r = 1.3 \mu\text{m}$, $\sigma_{r'} = 4.1 \mu\text{rad}$
 $\Sigma_x = 35 \mu\text{m}$, $\Sigma_{x'} = 22.4 \mu\text{rad}$, $\Sigma_y = 7.4 \mu\text{m}$, $\Sigma_{y'} = 4.2 \mu\text{rad}$
- Imaging vertical source on sample
 - source to focusing mirror 72.28 m
 - focusing mirror to sample 0.80 m
 - demagnification 90:1
- Size of image of vertical source at sample
 - aberration free image 0.19 μm FWHM
 - bimorph allows to shape mirror to required elliptical figure
 - aberrations determined by residual surface figure error
 - Gaussian figure error of 0.3 μrad rms creates beam size of 1.1 μm FWHM
 - convoluted size of image 1.1 μm FWHM

Size and Flux Estimates of Microbeam After APS Upgrade

Flux at sample

- Angular acceptance of horizontally focusing mirror
 - mirror length 300 mm, effective 200 mm
 - grazing angle 4 mrad
 - distance to source 72.68 m
 - angular acceptance from source 11.0 μ rad
 - angular divergence from source (FWHM) 52.6 μ rad

Angular acceptance of vertically focusing mirror

- mirror length 400 mm, effective 300 mm
- grazing angle 4 mrad
- distance to source 72.28 m
- angular acceptance from source 16.6 μ rad
- angular divergence from source (FWHM) 9.9 μ rad

Size and Flux Estimates of Microbeam After APS Upgrade

- Flux from undulator 8.1*10¹³ ph/s/0.1%BW
 - 200 mA beam current
 - 2.1m long (eff. 2.05 m), 3.1 cm magnetic period
 - at E_{phot} = 18 keV
 - into 11.0 μrad horizontal and 16.6 μrad vertical angle
- Si-220 double crystal bandwidth ~4.6*10⁻⁵
- Losses in windows, other 0.8
- Estimate of flux on sample 3.0*10¹² ph/s
- Estimate of flux density at sample 3*10¹⁸ ph/s/mm²
- Convergence angles of flux on sample
 - horizontal 1.6 mrad
 - vertical 0.9 mrad
- Exposure time to reach dose limit D_{1/2} = 4.3*10⁷ Gy 0.06 seconds

Gain with APS Upgrade for Microcrystal Macromolecular Crystallography

- Optical design: easier, less components
- Focal size: horizontally $\sim 1/2$
- Flux: 14-times ($3 \cdot 10^{12}$ ph/s)
- Flux density: 30-times ($3 \cdot 10^{18}$ ph/s/mm²)
- Sample life: 0.06 seconds instead of 2 seconds
- Increase in samples measured / hour: none
- Gain for microcrystal macromol. xtallography: little
- Gain worth 2 years shutdown: **NO**





Vibration Reduction and Beam Stabilization

- Vibration isolation base
 - heavy platform on springs
 - supports optical elements
 - reduces higher frequencies more than 40x
 - low natural frequencies (<5 Hz)
- Stabilization of vibration isolated platform
 - position sensors (platform vs. support frame)
(x-ray BPM design with laser, 0.5 μm sensitivity)
 - angle sensors (laser beam reflected from mirror on platform)
 - feedback to linear motors after low pass filter

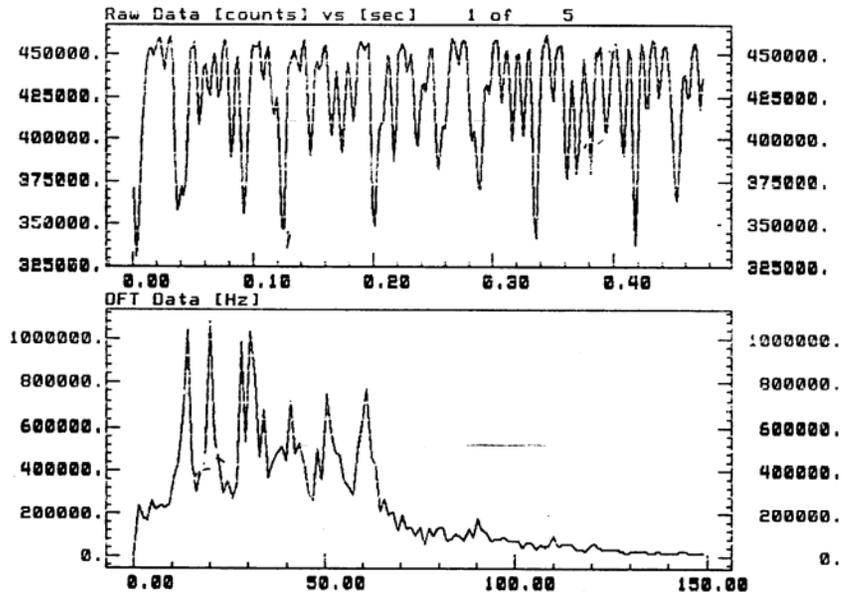
Vibration Reduction and Beam Stabilization

Stabilization of x-ray beam:

- X-ray tracking
 - white beam position monitor (hard x-ray BPM)
 - x-ray BPM before horizontally defining slits
 - x-ray BPM before mirrors
 - x-ray BPM before sample
- Optical tracking
 - laser beam parallel to x-ray beam path
 - mirrors on first and second crystal rotation axis
 - laser beam BPM before horizontally defining slits

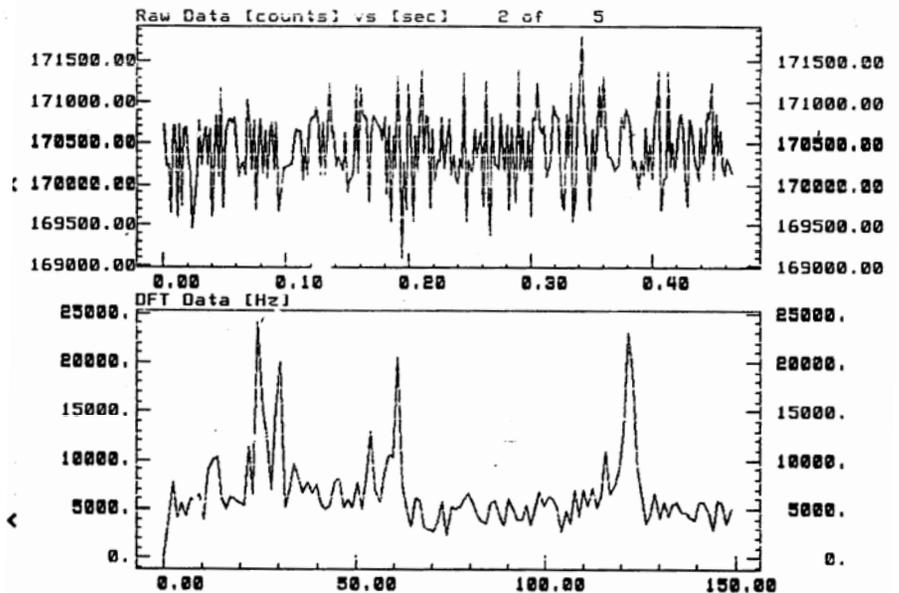
Vibration Isolation Base

Noise Spectrum without Vibration Isolation
Si-220 Crystal, Fully Tuned



Top: real time, 1 scan
Bottom: Fourier transform, average of 5 scans

Noise Spectrum with Vibration Isolation
Si-220 Crystal, Fully Tuned

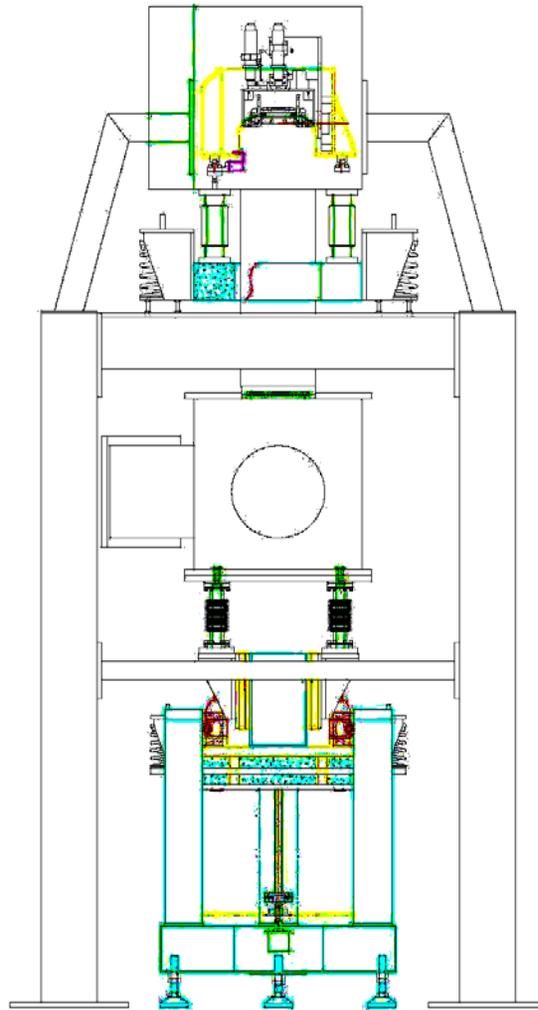


Top: real time, 1 scan
Bottom: Fourier transform, average of 5 scans

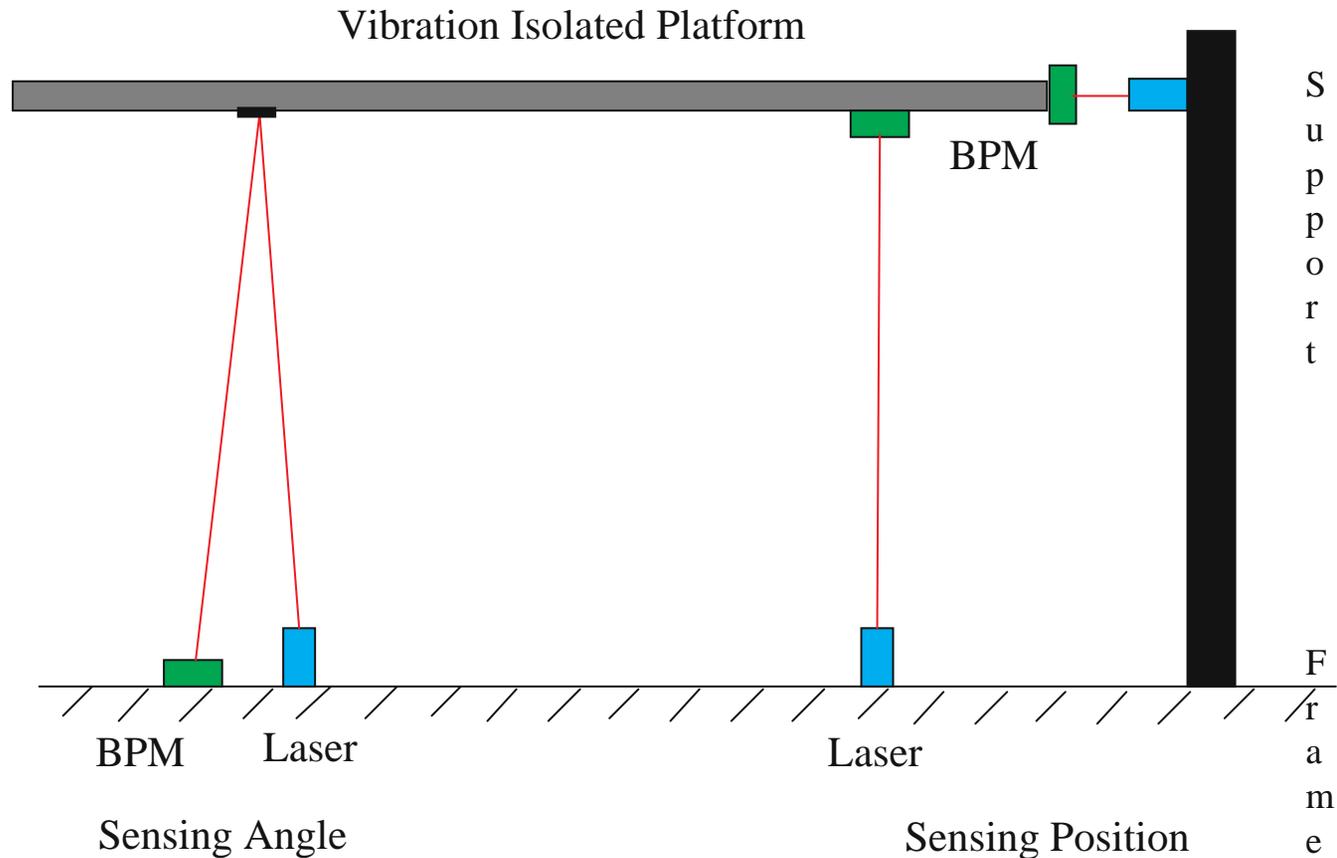
The vibration isolation system reduces the amplitudes of the vibration spectrum by a factor 40.

Three Undulator Beamlines Upgrade

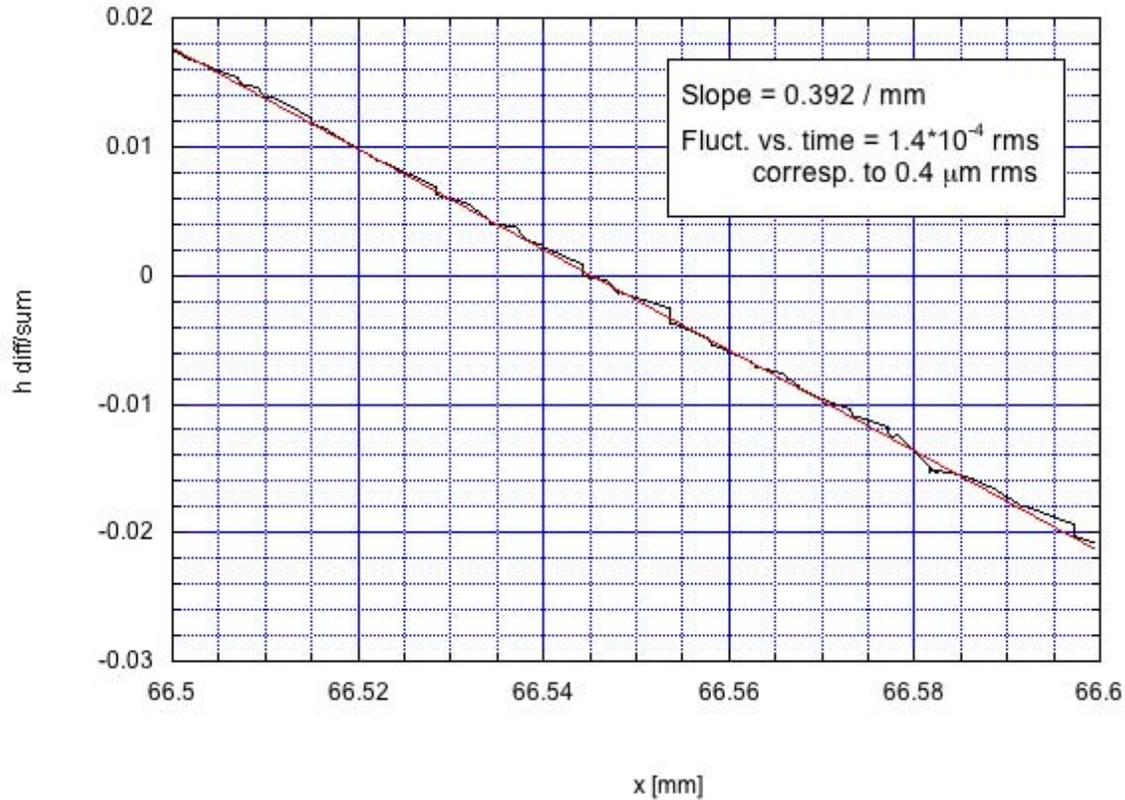
Vertically Offset Beamline, View in Beam Direction



Sensing Angle and Position of the Vibration Isolated Platform



Quad PIN Diode BPM Position Sensing



Laser BPM Signal For 0.1 mm Horizontal Scan

Construction Time Line

FY 2006	upgrade BM beamline start upgrade of center ID beamline
FY 2007	finish upgrade of center ID beamline start design & construction of triple ID beamlines
FY 2008	start modification of hutch 19-ID-C and 19-ID-D start construction of additional hutches
FY 2009	rebuilt center beamline 19-ID1 recommission 19-ID1 finish construction of triple ID beamlines
Summer 2010	commission new ID beamlines
Fall 2010	start user operation of new ID beamlines

Front End and Undulator Construction Timeline

- | | |
|---|--------------------------|
| 1. design modification of 2.1 m undulator for 3.1 cm period | 1 month |
| 2. fabrication of 2.1 m undulator with 3.1 cm period | 6 months |
| 3. design of 1 m undulator with 3.1 cm period | 6 months |
| 4. fabrication of two 1 m undulators with 3.1 cm period | 12 months |
| 5. design of triple undulators vacuum chamber | 3 months |
| 6. fabrication of triple undulator vacuum chamber | 6 months |
| 7. fabrication of two sets of deflector and steering magnets | 6 months |
| 8. fabrication of additional RF BPMs and electronics | 3 months |
| 9. design modification dual to triple undulator front end | 3 months |
| 10. fabrication of triple undulator front end | 6 months |
| 11. installation of 2.1 m undulator
and new vacuum chamber | during 1 month shut down |
| 12. installation of new front end | during 1 month shut down |
| 13. installation of two 1 m undulators | during 1 month shut down |

